

Contents

Contents	1
List of Figures	1
1 Introduction	2
2 Specifications	3
3 Operating Information	4
4 Theory of Operation	5
4.1 Block Description	5
4.2 Detailed Circuit Description	6
Power Input Circuit	6
Switching DC-DC Converters	8
Linear Regulators	9
Synthesizer	9
Synthesizer Output Amplifiers	10
Output System	11
Input System	11
Microcontroller	12
4.3 Software Description	12
Signal Processing	12
User Interface	12
5 Electrical parts	13
6 Full schematics	22
References	36

List of Figures

1	Block diagram	5
2	MOS reverse polarity protection circuit, simplified	6
3	UVLO and OVLO circuit	6
4	Miller integrator	7
5	USB power input circuit	8
6	Basic buck converter circuit	8
7	3.3 V buck converter circuit	9
8	DDS architecture	10
9	DDS output circuit	10
10	Output amplifier for synthesizer	10
11	GaAs switch circuit	11
12	GaAs control circuit	11

1 Introduction

2 Specifications

3 Operating Information

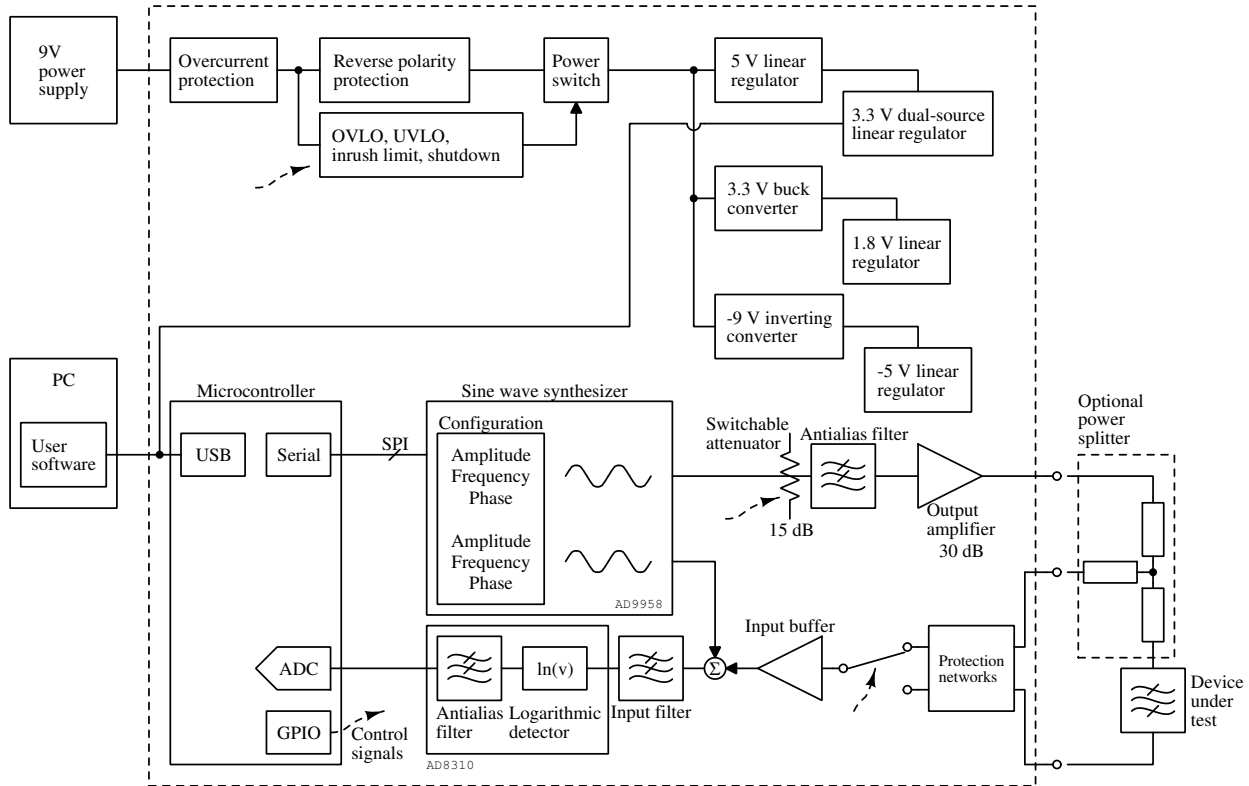


Figure 1: Block diagram

4 Theory of Operation

This section contains a description of the operation of the gain/phase analyzer. Explanations range from simple and broad to very specific. It is expected that the reader has an understanding of the basics of gain/phase analysis itself, which is explained in the [Introduction chapter](#).

Also, it will be beneficial to look at the main system schematics when reading through this section. Small pieces of the schematic are excerpted when helpful in explaining their function, but are not always shown.

4.1 Block Description

Relevant schematic page: [BlockDiagram/1](#)

The block diagram is shown in figure 1. A microcontroller drives the instrument, configuring a dual sine wave synthesizer via a serial interface. The first output passes through an optional, switchable attenuator, allowing output amplitude to be configured beyond the practical amplitude range of the synthesizer. The signal is then filtered

to attenuate Nyquist aliasing, and then amplified by 30 dB before being passed to the output.

Signals returning from the Device Under Test (DUT) pass through input protection networks, then enter a double-throw RF switch allowing one of them to be analyzed. An input buffer prevents signals from further circuitry from feeding back out the input and affecting the DUT. A summing network combines the input signal with the second output of the synthesizer, and the sum passes through an input filter and into a logarithmic detector. The logarithmic detector outputs a voltage corresponding to the signal amplitude in decibels, and this is further filtered to allow slow sampling, and returns to the microcontroller via the on-chip analog to digital converter.

A power supply system provides overcurrent protection, reverse polarity protection, overvoltage lockout, undervoltage lockout, inrush limiting, and microcontroller-driven shutdown (used in cases of USB suspend). It produces regulated voltage rails of +9 V and -9 V (for the final output amplifier stage), +5 V and -5 V (for general linear circuitry), +3.3 V (for the synthesizer), +1.8 V (for the synthesizer), and a second, weaker +3.3 V rail that can be powered by the USB port in the absence of the main power input (for the microcontroller).

A USB interface connects to a computer, where software sends control commands to the instrument and plots received data.

4.2 Detailed Circuit Description

Power Input Circuit

Relevant schematic page: [PowerInput/11](#)

This instrument is complex and has many somewhat expensive parts, so a full input subsystem was designed to ensure that these parts are always supplied correctly with power. This subsystem provides the following features:

- Overcurrent protection
- Reverse polarity protection
- Undervoltage lockout
- Overvoltage protection
- Inrush current limiting

Overcurrent protection

The first piece of this input system, and possibly the simplest, is R81. R81 is a *resettable fuse*, a type of resistor with a positive temperature coefficient. Its resistance is very low (around 0.5 Ω) at room temperature. As the current flowing through it increases, it heats up, and as it heats up, its resistance increases. Eventually, it will reach a point where this process ‘snowballs’, and its resistance is high enough that almost no current can flow through it. This allows it to act like a fuse, but without permanently blowing: as soon as it cools back down, it will conduct again.

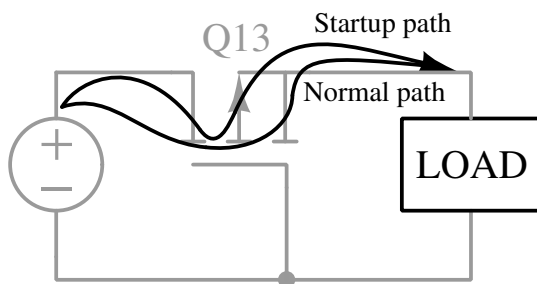


Figure 2: MOS reverse polarity protection circuit, simplified

Reverse polarity protection

Once input current has passed through the resettable fuse, it encounters Q13. A simplified form of this part of the circuit can be seen in figure 2. Remember that a MOSFET has ‘parasitic’ diodes connected from the transistor’s channel to its substrate; in a standard power MOSFET, one ends up connected between the two ends of the channel (the other ends up shorted to itself). In a P-channel MOSFET, this diode points from the source to the drain. In this circuit, when power is applied with the correct polarity, this diode allows current to initially take the path labeled *startup path*. When it does so, the voltage applied to the load begins to rise, but the gate stays low, as it is tied to ground. Eventually, the voltage rises high enough that the gate-source voltage switches on the MOSFET, and current begins to flow through the *normal path* instead. This path takes the current through the low-impedance MOSFET channel, rather than through the diode where the forward threshold voltage of the diode would be lost.

If power is applied in the incorrect polarity, the substrate diode never conducts, so the MOSFET never switches on.

Power switch

After the reverse polarity protection, the current must flow through Q14, which is connected as a traditional switch. R88 holds its gate and source together when the power is switched off, keeping the MOSFET also turned off.

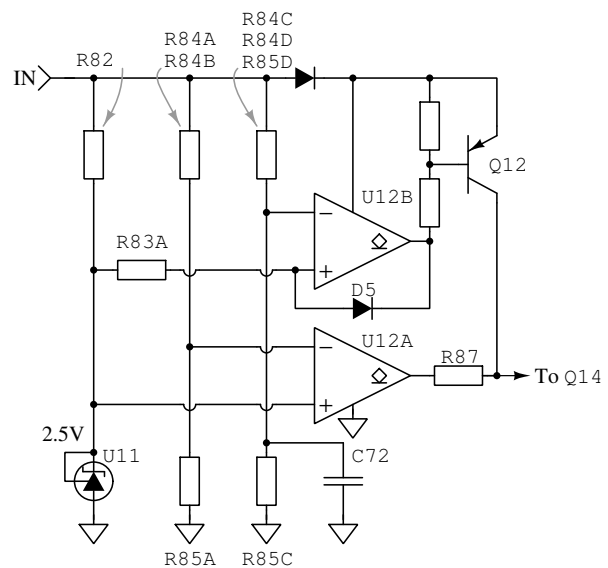


Figure 3: UVLO and OVLO circuit

To simplify things, the subcircuit in figure 3 is powered through a single diode for its own reverse-polarity protection. Bandgap voltage reference U11 does not need this, as its internal circuit has an antiparallel diode built in [10].

Undervoltage lockout

U11 provides an accurate 2.5 V level against which the input voltage can be compared. As the input voltage rises, the voltage at the output of the R84A/R84B/R85A voltage divider also rises. When this divided voltage reaches the 2.5 V reference level, the input voltage is at 7.5 V, the undervoltage threshold. Comparator U12A switches low, allowing power switch Q14 to switch on and allow the full system to operate.

Overvoltage protection

If the input voltage continues to rise, the voltage at the output of the R84C/R84D/R85D/R85C voltage divider will eventually reach the reference level when the input voltage is at 10 V. C72 provides a low-pass effect which prevents simple noise and short transients from causing this. When this happens, comparator U12B switches low. At this point, two things happen. First, Q12 switches Q14 off, powering down the circuit. Second, D5 pulls the reference level as seen by U12B down to about 1 V, locking the system in this shutdown mode until the input voltage drops back as low as 4 V — at which point it must climb again to the 7.5 V undervoltage threshold. In practice, the system must be powered off and back on. This latch prevents the instrument from accidentally being powered by too high an input voltage.

Inrush current limiting

Q14 does not act *only* as a power switch. When it switches on, it starts in the ‘cutoff’ region of operation, and moves to the ‘saturation’ region. However, it must pass through the ‘linear’ region. We can take advantage of this.

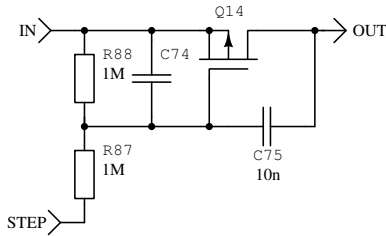


Figure 4: Miller integrator

The circuit in figure 4, when Q14 is in the linear region, is known as a ‘Miller integrator’ [2, pg. 283]. Because R87 and R88 form a voltage divider, the input voltage to the integrator will be half the input supply voltage at half the resistance (nominally, 4.5 V at 500 kΩ). The integrator capacitance is simply C75, which is 10 nF. Because the voltage across C74 changes only negligibly, its effect on the circuit will also be negligible.

At startup, C75 would tend to hold the gate above the source, switching the transistor fully on and bypassing any limiting effect. The much larger C74 swamps this effect, holding the gate to the source until a DC source of current is provided via R87.

The input signal to this integrator will be a step, because comparator U12A switches directly from ‘off’ to ‘on’. Integrating a step gives a ramp, with a slope of:

$$\frac{dv}{dt} = \frac{v_{in}}{RC} = \frac{4.5 \text{ V}}{(500 \text{ k}\Omega)(10 \text{ nF})} = 900 \text{ V/s} = 0.9 \text{ V/ms}$$

This means it will take about 10 ms for the voltage to ramp from zero to the full input voltage of 9 V.

Because the inrush current to be limited is the current charging the system’s capacitance, we can calculate the worst-case inrush current. Charge is held on-board by approximately 200 μF worth of capacitors. Given this capacitance and the voltage slope, the current is calculated as follows:

$$I = C \frac{dv}{dt} = (200 \text{ }\mu\text{F})(900 \text{ V/s}) = 180 \text{ mA}$$

During this charging time, the power dissipated in Q14 will be high. The worst-case is when the full input voltage is dropped across it, giving a power dissipation of $(9 \text{ V})(180 \text{ mA}) = 1.62 \text{ W}$. The average power for the entire time will be:

$$\begin{aligned} P &= IV \\ P_{\text{avg}} &= \frac{1}{10 \text{ ms}} \int_0^{10 \text{ ms}} i v \, dt \\ &= \frac{1}{2} (1.62 \text{ W})(10 \text{ ms}) / (10 \text{ ms}) \\ &= 810 \text{ mW} \end{aligned}$$

Thus, a MOSFET must be selected that can handle an 810 mW pulse for 10 ms. This pulse-handling capability is shown in the datasheet as the “forward-biased safe operating area”, and we selected an AOD417 which can easily handle this pulse with excess [1].

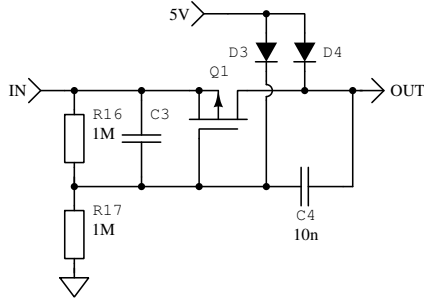


Figure 5: USB power input circuit

USB Power Input Circuit

Relevant schematic page: [Comm/2](#)

The USB specification is very demanding with respect to the amount of inrush current that a USB device may consume. We used the same Miller-integrator inrush limiting circuit on the USB power supply input.

In this case, the resistance has not changed (still a Thévenin-equivalent 500 kΩ), and the input step is equal to 2.5 V, half the input voltage. The integrating capacitance is C4, which has a value of 10 nF, and the maximum input capacitance being charged is approximately 20 μF.

$$\frac{dv}{dt} = \frac{v_{in}}{RC} = \frac{2.5 \text{ V}}{(500 \text{ k}\Omega)(10 \text{ nF})} = 500 \text{ V/s}$$

$$I = C \frac{dv}{dt} = (20 \text{ }\mu\text{F})(500 \text{ V/s}) = 10 \text{ mA}$$

The power dissipation in this case is very small (no more than 50 mW for only a few milliseconds), so we used a smaller and less expensive MOSFET that was already in use elsewhere for this particular integrator.

No reverse polarity protection was deemed necessary on the USB input.

Diodes D3 and D4 allow the on-board power supply to power the circuitry downstream from the USB port whenever that supply is powered, so that this circuitry can draw larger amounts of current without the trouble of making sure that this current draw is within USB specifications. D3 shuts off Q1, and D4 provides power in Q1's absence.

Switching DC-DC Converters

Relevant schematic page: [DCDC/12](#)

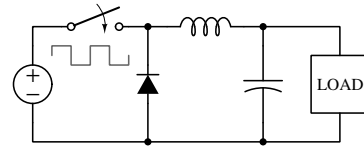


Figure 6: Basic buck converter circuit

Buck converter theory

The basic idea of an inductor is that it translates electric current flowing through it into a magnetic field around it. There is energy stored in this magnetic field, so the inductor tends to hold the current fixed (as changing the current would require adding or removing energy from the field). The 'buck converter' is a voltage down-converter circuit that takes advantage of this.

A more mathematical approach is that inductors integrate the voltage applied to them, producing a current:

$$i = \frac{1}{L} \int v \, dt$$

A buck converter must have at least one switch, as shown in figure 6. The switch is initially closed for a brief period. This applies a positive voltage to the inductor, causing the current through it to begin to increase (remember that the integral of a step is a ramp). This current flows through to the output of the converter, and the output voltage begins to rise.

Now, the switch is opened. The inductor keeps the current flowing, though, through the diode this time. The voltage across the inductor is now negative (the voltage on the left side had to fall negative in order to forward-bias the diode and make it conduct), so the current starts ramping downward, and the output voltage begins to fall. [5, pp. 356–357]

By repeating this cycle, the output voltage can be made to rise and fall around a desired point, and by placing a large capacitor at the output, the rising and falling current can translate to very small variation in output voltage, though it must rise and fall at least a small amount. This allows the output voltage to be any arbitrary voltage smaller than the input voltage, but does not theoretically lose power, unlike a linear regulator (whose entire mechanism of operation is intentional power loss).

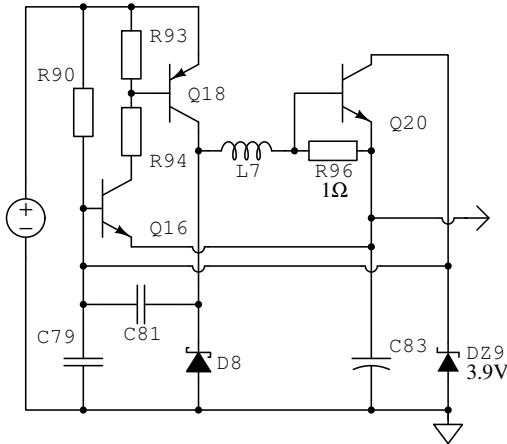


Figure 7: 3.3 V buck converter circuit

3.3 V buck converter

In this instrument, we have used a simple, three-transistor regulated buck converter circuit. It is inexpensive, reliable, and though it is not hugely efficient, it generates relatively little switching noise (due, in part, to its low speed compared to more modern designs).

In the first phase of the switching cycle, Q16's base voltage is low. R90 charges C79, and eventually the base voltage rises high enough that Q16 switches on. It pulls Q18's base voltage down, switching on that transistor too. Q18 is equivalent to the main switch in figure 6, and the inductor current starts to rise.

In the next phase of the switching cycle, something draws current towards ground out of C79 and away from Q16's base. This starts a chain reaction: Q16 and Q18 start to switch off, and are no longer driving the inductor. The inductor's tendency to keep current flowing makes the voltage on its left side sharply decrease. This decrease is coupled through C81, which drags Q16's base voltage even lower, switching it off quite solidly. The converter will remain switched off until C79 charges back up through its resistor.

Two things can be the 'something' of the previous paragraph, initiating the switch from phase 1 to phase 2. First, note that Q16's emitter is connected to the output voltage, so when it is switched on, its base will be about 0.65 V above that. When the output voltage reaches about 3.25 V, the base voltage is at about 3.9 V, and Zener diode DZ9 starts to conduct. This means that the output voltage will not be allowed to rise above about 3.25 V, providing the voltage regulation function.

The inductor current must also flow through sense resistor R96. If the current exceeds about 650 mA, the base-emitter voltage applied to Q20 will be high enough

to switch it on, and Q20 will draw the shutdown current. This provides the current-limiting function.

-9V inverting regulator

It is possible to repurpose a buck converter circuit as an inverting (buck-boost) circuit that generates a negative voltage [11]. The circuit is otherwise the same, with two exceptions. First, the Zener diode, now DZ10, is a 10 V part, giving a regulated output voltage of about 9.35 V. Second, because the current through the output capacitor has more hard edges in a buck-boost converter, a 1 μ F ceramic capacitor (useful to higher frequencies and currents) has been added in parallel with the main output capacitor.

Linear Regulators

A series-type linear regulator works by acting as a controlled resistance, regulating itself to exactly the resistance required to give the correct output voltage considering the amount of current flowing through it. This means that power loss is a required property of linear regulators. For example, a linear regulator taking an input voltage of 9 V, giving an output voltage of 5 V, and passing a current of 100 mA, will lose $(9 - 5)(0.1) \text{ W} = 400 \text{ mW}$ of power, dissipated as heat. The loss is sometimes a fair trade for simplicity and low output noise. This instrument uses four linear regulators, which provide power supplies of 5 V, -5 V, 1.8 V, and a low-power 3.3 V supply (a high-power 3.3 V supply for the synthesizer comes from the buck converter).

These regulators are U13, U14, U15, and U16. They are monolithic devices with no external circuitry except for filter capacitors, and as such will not be addressed further. See their datasheets for more information: [9] [8] [4] [7].

Synthesizer

Relevant schematic page: [Synth/3](#)

In order to generate the test signals, a pair of sinusoids at anywhere from 1 kHz to above 150 MHz, the instrument uses a sophisticated high-speed Direct Digital Synthesis (DDS) integrated circuit.

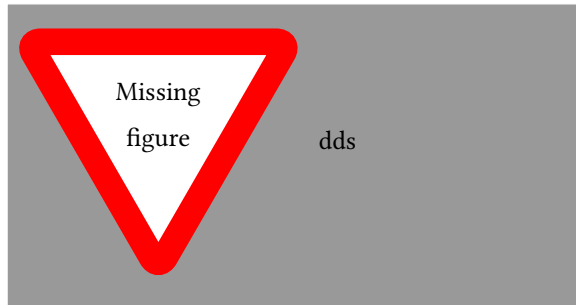


Figure 8: DDS architecture

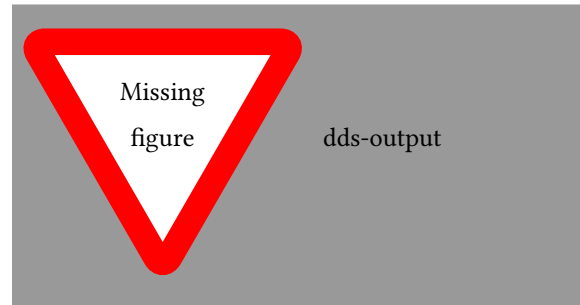


Figure 9: DDS output circuit

Figure 8 shows the internal architecture of the chip, somewhat simplified from the version in the datasheet [3]. In each of the two independent waveform generators, a ‘frequency tuning word’ (a 32-bit unsigned integer) is repeatedly added to an accumulator at a rate of 500 MHz. This causes the accumulator to increment, and overflow, at a higher rate for higher tuning words. This sum is added to a phase offset, which allows each signal to be independently offset from the other. This constantly incrementing and resetting count is applied to a lookup table loaded with cosine values, converting it from a digital ramp to a digital sinusoid. It is next multiplied by an amplitude control value, and loaded into a digital-to-analog converter (DAC) to generate the analog, sinusoidal waveform.

This integrated circuit is intended for radio applications. As such, it has advanced features that this instrument does not require. It can be supplied externally with a stable 500 MHz clock signal from a high quality clock generator, but because we do not require such extreme stability, we are instead using its internal Phase-Locked Loop (PLL) to multiply the clock signal from a 25 MHz quartz crystal, X1, up to the full internal clock frequency. Also, the device can generate modulated waveforms using a 4-bit digital modulation input; these inputs are not used.

Synthesizer Output Amplifiers

Relevant schematic page: [Synth/3](#)

As is often the case with high-speed integrated circuits, the DDS chip has a peculiar output system.

The outputs are symmetric current sinks, which pull up to 9.9 mA down from AVDD (1.8 V), and the voltage that appears at these outputs must not deviate by more than 500 mV from AVDD (or else the signal will distort severely). The intended application is for these to be connected to a center-tapped transformer, with the center tap connected to AVDD. This is impractical due to the frequency range required: any transformer with a high enough inductance to operate at 1 kHz has too much parasitic capacitance to operate at 150 MHz. Instead, a DC-coupled differential amplifier was used, with carefully designed termination networks to provide the correct voltage range.

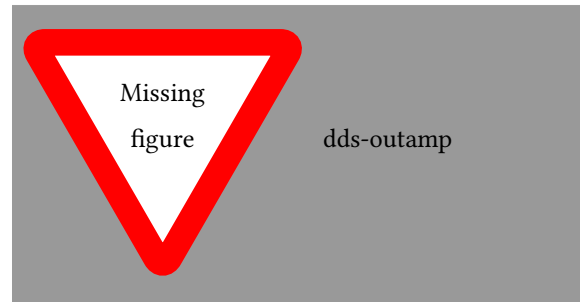


Figure 10: Output amplifier for synthesizer

The $49.9\ \Omega$ resistors terminate the transmission line at the source. The amplifier’s inputs are relatively low impedance, so $53.6\ \Omega$ resistors were used as load termination to provide a more accurate impedance when placed in parallel with the differential amplifier.

Note that the input impedances of the two sides of the differential amplifier are not equal. On the side entering the noninverting (‘positive’) input, the impedance to ground is the sum of the two input resistors, or $720\ \Omega$. However, on the other side, the end of the feedback chain is not grounded, it is a 180° phase-shifted copy of the input signal. The equivalent input impedance here is only $360\ \Omega$, and a more proper termination resistor there

would be $57.6\ \Omega$. However, these transmission lines are very short, and the difference in impedance does not make a significant difference. Using two different resistors here would have increased the design complexity and cost, and was deemed unnecessary.

Output System

Relevant schematic page: [OutputAmp/4](#)

Attenuator and Filter

Gain Stages and Termination

Input System

Relevant schematic page: [InputFrontend/6](#)

Protection

Relevant schematic page: [Protection/7](#)

Switching

Relevant schematic page: [Switching/8](#)

It would not be practical for the analyzer to contain two independent input subsystems to measure both inputs, as these systems are complex and expensive, and there would be significant variation between the two. Instead, one input subsystem is switched between two inputs. This switching is accomplished with a pair of high-bandwidth SPST RF analog switches.

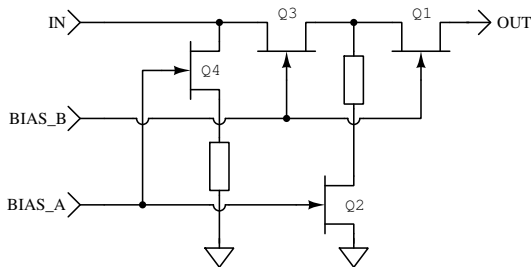


Figure 11: GaAs switch circuit

Figure 11 shows the internal circuit of the switch [6]. It is a simple circuit built from four gallium arsenide (GaAs) FETs¹. These are depletion-mode devices, so they are switched *on* by applying zero volts to the gate, and turned *off* by applying a negative voltage, around -5 V . Switching on transistors Q1 and Q3 allows the signal to pass through from the input to the output. Switching on transistors Q2 and Q4 disconnects the input from the output, but also *terminates* the input (applies a $50\ \Omega$ resistance between the input and ground). This is important to make sure that a disconnected input does not cause signal reflections.

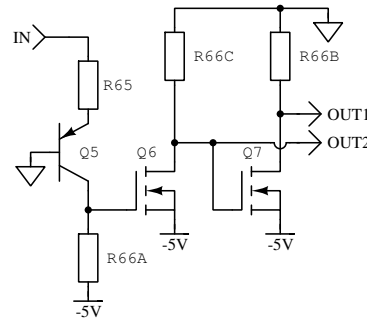


Figure 12: GaAs control circuit

Figure 12 is the control circuit for figure 11. When 0 V (a logic *low*) is applied to the input from the microcontroller, no current flows through R65 or R66A. This applies -5 V to Q6. Because Q6's source is connected to the -5 V rail instead of ground, the voltage between gate and source (V_{GS}) is zero, and Q6 is switched off. This provides 0 V to one input of the GaAs switches. Q7 acts as an inverter, providing -5 V to the other GaAs switch input. The dual switches have their inputs connected opposite each other, so this switches one of them *on* and the other *off*.

When 3.3 V (a logic *high*) is applied to the input from the microcontroller, about 1.6 mA flows through R65. This saturates Q5, applying about 0.7 V to Q6. As above, V_{GS} is the difference between this and the -5 V rail, or 5.7 V . Q6 now switches on, and the two signals to the GaAs switches swap places. This swaps the two switches, turning on the one that was off, and turning off the one that was on.

Buffer and Filter

¹The type of FET used is a relatively uncommon variant called a *MESFET*, or *MEtal-Semiconductor Field Effect Transistor*. This is a variant on the well known *JFET*, using a Schottky junction instead of a PN junction. While uncommon in general, it is used often in GaAs circuits due to the relative ease of constructing GaAs MESFETs.

Relevant schematic page: [Buffer_Filter/9](#)

Logarithmic Detector

Relevant schematic page: [Detector/10](#)

Microcontroller

Relevant schematic page: [MPU/13](#)

USB Communications

Relevant schematic page: [Comm/2](#)

4.3 Software Description

Signal Processing

Sampling

Null Search

Calibration

User Interface

5 Electrical parts

Reference	Manufacturer	Part Number	Line	Description
C1			CAP MLCC 10n 50V 10% \geq X5R [0603]	
C2			CAP MLCC 10n 50V 10% \geq X5R [0603]	
C3			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C4			CAP MLCC 10n 50V 10% \geq X5R [0603]	
C5			CAP MLCC 10 μ 10V 10% \geq X5R [0805]	
C8			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C9			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C10			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C11			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C12			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C13			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C14			CAP MLCC 15p 50V 10% C0G [0603]	
C15			CAP MLCC 15p 50V 10% C0G [0603]	
C16			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C17			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C18			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C19			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C20			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C21			CAP MLCC 100n 20V 10% \geq X7R [0805]	
C22			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C23			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C24			CAP MLCC 100n 20V 10% \geq X7R [0805]	
C25			CAP MLCC 680p 16V 5% C0G [0603]	
C26			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C27			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C28			CAP MLCC 10 μ 10V 10% \geq X5R [0805]	
C29			CAP MLCC 10 μ 10V 10% \geq X5R [0805]	
C30			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C31			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C32			CAP MLCC 1n 50V 10% C0G [0603]	
C33			CAP MLCC 1n 50V 10% C0G [0603]	
C34			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C35			CAP MLCC 100n 16V 10% \geq X7R [0603]	

Reference	Manufacturer	Part Number	Line	Description
C36			CAP MLCC 10μ 10V 10% ≥X5R [0805]	
C37			CAP MLCC 10μ 10V 10% ≥X5R [0805]	
C38			CAP MLCC 100n 20V 10% ≥X7R [0805]	
C39			CAP MLCC 100n 20V 10% ≥X7R [0805]	
C40			CAP MLCC 10μ 25V 10% ≥X5R [1206]	
C41			CAP MLCC 10μ 25V 10% ≥X5R [1206]	
C43	Murata	GRM1555C1H220GA01D	DIST DIGIKEY 490-6219-1-ND	CAP MLCC 22pF C0G [0402]
C44	Murata	GRM1555C1H220GA01D	DIST DIGIKEY 490-6219-1-ND	CAP MLCC 22pF C0G [0402]
C45	Samsung	CL10C1R5BB8NNNC	DIST DIGIKEY 1276-1656-1-ND	CAP MLCC 1.5pF C0G [0402]
C46	Samsung	CL05C560JB5NNNC	DIST DIGIKEY 1276-1707-1-ND	CAP MLCC 56pF C0G [0402]
C47	Samsung	CL05C4R7CB5NNNC	DIST DIGIKEY 1276-1703-1-ND	CAP MLCC 4.7pF C0G [0402]
C48	Samsung	CL05C4R7CB5NNNC	DIST DIGIKEY 1276-1703-1-ND	CAP MLCC 4.7pF C0G [0402]
C49	Samsung	CL05C560JB5NNNC	DIST DIGIKEY 1276-1707-1-ND	CAP MLCC 56pF C0G [0402]
C50	Samsung	CL05C4R7CB5NNNC	DIST DIGIKEY 1276-1703-1-ND	CAP MLCC 4.7pF C0G [0402]
C51	Murata	GRM1555C1H220GA01D	DIST DIGIKEY 490-6219-1-ND	CAP MLCC 22pF C0G [0402]
C52	Murata	GRM1555C1H220GA01D	DIST DIGIKEY 490-6219-1-ND	CAP MLCC 22pF C0G [0402]
C53			CAP MLCC 47μ 10V 20% ≥X5R [1206]	
C54			CAP MLCC 1n 50V 10% C0G [0603]	
C55			CAP MLCC 100n 20V 10% ≥X7R [0805]	
C56			CAP MLCC 10n 50V 10% ≥X5R [0603]	
C57			CAP MLCC 1n 50V 10% C0G [0603]	
C58			CAP MLCC 1n 50V 10% C0G [0603]	
C59			CAP MLCC 100n 16V 10% ≥X7R [0603]	
C60	TDK	C1608C0G1H220F080AA	DIST DIGIKEY 445-5366-1-ND	CAP MLCC 22pF C0G [0402]
C61	TDK	C1608C0G1H330F080AA	DIST DIGIKEY 445-7027-1-ND	CAP MLCC 33pF C0G [0402]
C62	TDK	C1608C0G1H220F080AA	DIST DIGIKEY 445-5366-1-ND	CAP MLCC 22pF C0G [0402]
C63			CAP MLCC 10n 50V 10% ≥X5R [0603]	
C64	TDK	C2012JB1H105K085AB	DIST DIGIKEY 445-11490-1-ND	CAP MLCC 1uF [0805]
C65			CAP MLCC 10n 50V 10% ≥X5R [0603]	
C66	TDK	C2012JB1H105K085AB	DIST DIGIKEY 445-11490-1-ND	CAP MLCC 1uF [0805]
C67			CAP MLCC 10n 50V 10% ≥X5R [0603]	
C68			CAP MLCC 100n 16V 10% ≥X7R [0603]	
C69			CAP MLCC 47μ 10V 20% ≥X5R [1206]	
C70			CAP MLCC 220p 16V 5% C0G [0603]	
C71			CAP MLCC 330n 50V 10% ≥X7R [0603]	
C72			CAP MLCC 10n 50V 10% ≥X5R [0603]	
C73			CAP MLCC 100n 20V 10% ≥X7R [0805]	

Reference	Manufacturer	Part Number	Line	Description
C74			CAP MLCC 100n 20V 10% \geq X7R [0805]	
C75			CAP MLCC 10n 50V 10% \geq X5R [0603]	
C76	Panasonic	16SVPC100M	DIST DIGIKEY P16468CT-ND	CAP ALU-POLY 100uF 16V
C77	Panasonic	16SVPC100M	DIST DIGIKEY P16468CT-ND	CAP ALU-POLY 100uF 16V
C78			CAP MLCC 10n 50V 10% \geq X5R [0603]	
C79			CAP MLCC 10n 50V 10% \geq X5R [0603]	
C80			CAP MLCC 1n 50V 10% C0G [0603]	
C81			CAP MLCC 1n 50V 10% C0G [0603]	
C82	Panasonic	16SVPC100M	DIST DIGIKEY P16468CT-ND	CAP ALU-POLY 100uF 16V
C83	Panasonic	16SVPC100M	DIST DIGIKEY P16468CT-ND	CAP ALU-POLY 100uF 16V
C84			CAP MLCC 1 μ 16V 10% \geq X5R [1206]	
C85			CAP MLCC 1 μ 16V 10% \geq X5R [1206]	
C86			CAP MLCC 1 μ 16V 10% \geq X5R [1206]	
C87			CAP MLCC 1 μ 16V 10% \geq X5R [1206]	
C88			CAP MLCC 1 μ 10V 10% \geq X5R [0805]	
C89			CAP MLCC 1 μ 16V 10% \geq X5R [1206]	
C90			CAP MLCC 10 μ 10V 10% \geq X5R [0805]	
C91			CAP MLCC 10 μ 10V 10% \geq X5R [0805]	
C92			CAP MLCC 22 μ 6V 10% \geq X5R [0805]	
C93			CAP MLCC 1 μ 10V 10% \geq X5R [0805]	
C97			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C98			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C100			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C101			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C102			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C103			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C104			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C105			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C106			CAP MLCC 100n 16V 10% \geq X7R [0603]	
C107			CAP MLCC 10 μ 10V 10% \geq X5R [0805]	
C108			CAP MLCC 10 μ 10V 10% \geq X5R [0805]	
C109			CAP MLCC 1 μ 10V 10% \geq X5R [0805]	
C110			CAP MLCC 15p 50V 10% C0G [0603]	
C111			CAP MLCC 15p 50V 10% C0G [0603]	
D3			SEMI GENERIC MMBD4148	
D4			SEMI GENERIC MMBD4148	
D5			SEMI GENERIC MMBD4148	

Reference	Manufacturer	Part Number	Line	Description
D6			SEMI GENERIC MMBD4148	
D7			SEMI GENERIC MBR0540	
D8			SEMI GENERIC MBR0540	
DS1			SEMI GENERIC LED RED [3mm]	
DS2			SEMI GENERIC LED RED [0603]	
DS3			SEMI GENERIC LED RED [0603]	
DS4			SEMI GENERIC LED RED [0603]	
DS5			SEMI GENERIC LED RED [0603]	
DS6			SEMI GENERIC LED RED [0603]	
DS7			SEMI GENERIC LED RED [0603]	
DS8			SEMI GENERIC LED RED [0603]	
DS9			SEMI GENERIC LED RED [0603]	
DS10			SEMI GENERIC LED RED [0603]	
DS11			SEMI GENERIC LED RED [0603]	
DZ1			SEMI ONSEMI 1SMA5914BT3G	
DZ2			SEMI LITTELFUSE SP0503BAHT	
DZ3			SEMI ONSEMI ESD9L5.0ST5G	
DZ4			SEMI ONSEMI ESD9L5.0ST5G	
DZ5			SEMI GENERIC BZX84C2V7	
DZ6			SEMI GENERIC BZX84C2V7	
DZ7			SEMI ONSEMI ESD9L5.0ST5G	
DZ8			SEMI ONSEMI ESD9L5.0ST5G	
DZ9			SEMI GENERIC BZX84C3V9	
DZ10			SEMI GENERIC BZX84C10	
E1	Laird	HZ0805B222R-10	DIST DIGIKEY 240-2562-1-ND	FERRITE CHIP 2.2k @ 100MHz [0805]
E2	Laird	HZ0805B222R-10	DIST DIGIKEY 240-2562-1-ND	FERRITE CHIP 2.2k @ 100MHz [0805]
E5	Bourns	MZ1608-102Y	DIST DIGIKEY MZ1608-102YCT-ND	FERRITE CHIP 1k @ 100MHz [0603]
J1	CUI	PJ-037A	DIST DIGIKEY CP-037A-ND	CONN BARREL 2x6.5MM
J2	TE	5-1814400-1	DIST DIGIKEY A97593-ND	CONN SMA RIGHTANGLE FEMALE
J3	TE	5-1814400-1	DIST DIGIKEY A97593-ND	CONN SMA RIGHTANGLE FEMALE
J4	TE	5-1814400-1	DIST DIGIKEY A97593-ND	CONN SMA RIGHTANGLE FEMALE
J6	FCI	10118194-0001LF	DIST DIGIKEY 609-4618-1-ND	CONN USB MICRO-B FEMALE
J8	ONSHORE	302-S201	DIST DIGIKEY ED10524-ND	HEADER 2x10 100MIL SHROUDED
L1	Samsung	CIH05T56NJNC	DIST DIGIKEY 1276-6281-1-ND	IND CHIP 56nH
L2	Samsung	CIH05T47NJNC	DIST DIGIKEY 1276-6280-1-ND	IND CHIP 47nH
L3	Samsung	CIH05T47NJNC	DIST DIGIKEY 1276-6280-1-ND	IND CHIP 47nH
L4	Panasonic	ELJ-RF39NGFB	DIST DIGIKEY PCD1917CT-ND	IND CHIP 39nH

Reference	Manufacturer	Part Number	Line	Description
L5	Panasonic	ELJ-RF39NGFB	DIST DIGIKEY PCD1917CT-ND	IND CHIP 39nH
L6	Bourns	RLB0914-221KL	DIST DIGIKEY RLB0914-221KL-ND	IND WOUND 220uH 700mA
L7	Bourns	RLB0914-221KL	DIST DIGIKEY RLB0914-221KL-ND	IND WOUND 220uH 700mA
L8	TDK	MLZ2012M4R7HT000	DIST DIGIKEY 445-8659-1-ND	IND CHIP 4.7uH 300mA [0805]
L9	TDK	MLZ2012M4R7HT000	DIST DIGIKEY 445-8659-1-ND	IND CHIP 4.7uH 300mA [0805]
L10	TDK	MLZ2012M4R7HT000	DIST DIGIKEY 445-8659-1-ND	IND CHIP 4.7uH 300mA [0805]
MP5	Laird	BMI-S-203-C	DIST DIGIKEY 903-1015-ND	RF SHIELD TWO-PIECE
MP5	Laird	BMI-S-203F	DIST DIGIKEY 903-1052-1-ND	RF SHIELD TWO-PIECE
Q1			SEMI IRF IRLML6402	
Q2			SEMI GENERIC MMBT3906	
Q3			SEMI GENERIC 2N7002	
Q4			SEMI GENERIC 2N7002	
Q5			SEMI GENERIC MMBT3906	
Q6			SEMI GENERIC 2N7002	
Q7			SEMI GENERIC 2N7002	
Q8			SEMI GENERIC MMBT3904	
Q9			SEMI NXP BFR540	
Q10			SEMI NXP BFR540	
Q11			SEMI GENERIC MMBT3904	
Q12			SEMI GENERIC MMBT3906	
Q13			SEMI IRF IRLML6402	
Q14			SEMI AOS AOD417	
Q15			SEMI GENERIC MMBT3904	
Q16			SEMI GENERIC MMBT3904	
Q17			SEMI GENERIC PZT2907A	
Q18			SEMI GENERIC PZT2907A	
Q19			SEMI GENERIC MMBT3904	
Q20			SEMI GENERIC MMBT3904	
R1			RES SMD 3k3 5% [0603]	
R2			RES SMD 1k6 1% [0603]	
R3			RES SMD 1k6 1% [0603]	
R4			RES SMD 3k3 5% [0603]	
R5			RES SMD 1k6 1% [0603]	
R6			RES SMD 1k6 1% [0603]	
R7			RES SMD 1k6 1% [0603]	
R8			RES SMD 3k3 5% [0603]	
R9			RES SMD 3k3 5% [0603]	

Reference	Manufacturer	Part Number	Line	Description
R10	Bel Fuse	0ZCJ0005FF2E	DIST DIGIKEY 507-1793-1-ND	PPTC 50mA/150mA 60V [1206]
R11	Bel Fuse	0ZCJ0005FF2E	DIST DIGIKEY 507-1793-1-ND	PPTC 50mA/150mA 60V [1206]
R12	Bel Fuse	0ZCJ0005FF2E	DIST DIGIKEY 507-1793-1-ND	PPTC 50mA/150mA 60V [1206]
R13			RES SMD 1M 5% [0603]	
R14			RES SMD 30 1% [0603]	
R15			RES SMD 30 1% [0603]	
R16			RES SMD 1M 5% [0603]	
R17			RES SMD 1M 5% [0603]	
R18			RES SMD 49R9 1% [0603]	
R19			RES SMD 1k91 1% [0603]	
R21			RES SMD 49R9 1% [0603]	
R22			RES SMD 49R9 1% [0603]	
R23			RES SMD 49R9 1% [0603]	
R24			RES SMD 53R6 1% [0603]	
R25			RES SMD 53R6 1% [0603]	
R26			RES SMD 53R6 1% [0603]	
R27			RES SMD 53R6 1% [0603]	
R28			RES SMD 360 1% [0603]	
R29			RES SMD 360 1% [0603]	
R30			RES SMD 360 1% [0603]	
R31			RES SMD 360 1% [0603]	
R32			RES SMD 360 1% [0603]	
R33			RES SMD 360 1% [0603]	
R34			RES SMD 360 1% [0603]	
R35			RES SMD 360 1% [0603]	
R36			RES SMD 1k91 1% [0603]	
R37			RES SMD 1k91 1% [0603]	
R38			RES SMD 49R9 1% [0603]	
R39			RES SMD 49R9 1% [0603]	
R40			RES SMD 1k6 1% [0603]	
R41	Yageo	YC164-JR-0710KL	DIST DIGIKEY YC164J-10KCT-ND	RESPACK SMD 10k 5% [4x0603]
R42			RES SMD 200 1% [0603]	
R43			RES SMD 200 1% [0603]	
R45			RES SMD 30 1% [0603]	
R46			RES SMD 49R9 1% [0603]	
R47			RES SMD 150 1% [0603]	
R48			RES SMD 750 1% [0603]	

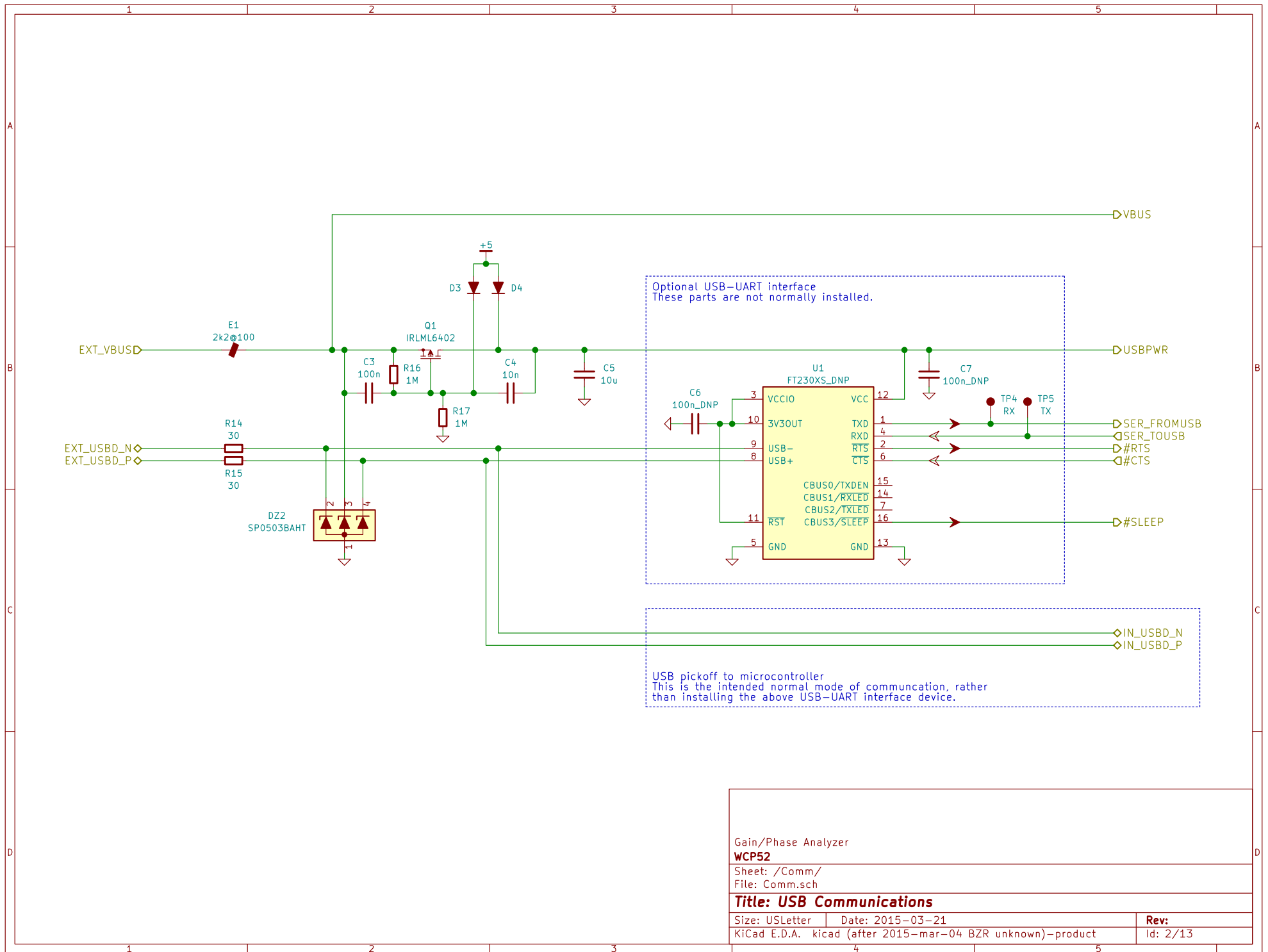
Reference	Manufacturer	Part Number	Line	Description
R49			RES SMD 150 1% [0603]	
R50			RES SMD 33 1% [0603]	
R51			RES SMD 33 1% [0603]	
R52			RES SMD 33 1% [0603]	
R53			RES SMD 33 1% [0603]	
R54			RES SMD 33 1% [0603]	
R55			RES SMD 33 1% [0603]	
R56			RES SMD 49R9 1% [0603]	
R57			RES SMD 1k6 1% [0603]	
R58			RES SMD 1k6 1% [0603]	
R59			RES SMD 3R3 10% [0603]	
R60			RES SMD 750 1% [0603]	
R61			RES SMD 750 1% [0603]	
R62			RES SMD 1k6 1% [0603]	
R63			RES SMD 1k6 1% [0603]	
R64			RES SMD 3R3 10% [0603]	
R65			RES SMD 1k6 1% [0603]	
R66	Yageo	YC164-JR-0710KL	DIST DIGIKEY YC164J-10KCT-ND	RESPACK SMD 10k 5% [4x0603]
R67			RES SMD 200 1% [0603]	
R68			RES SMD 200 1% [0603]	
R69			RES SMD 200 1% [0603]	
R70			RES SMD 200 1% [0603]	
R71			RES SMD 200 1% [0603]	
R72			RES SMD 200 1% [0603]	
R73			RES SMD 1k6 1% [0603]	
R74			RES SMD 30 1% [0603]	
R75			RES SMD 100 1% [0603]	
R76			RES SMD 100 1% [0603]	
R77			RES SMD 100 1% [0603]	
R78			RES SMD 3k3 5% [0603]	
R79			RES SMD 53R6 1% [0603]	
R80			RES SMD 49R9 1% [0603]	
R81	BelFuse	0ZCJ0035AF2E	DIST DIGIKEY 507-1801-1-ND	PPTC 350mA/750mA 30V [1206]
R82			RES SMD 3k3 5% [0603]	
R83	Yageo	YC164-JR-0710KL	DIST DIGIKEY YC164J-10KCT-ND	RESPACK SMD 10k 5% [4x0603]
R84	Yageo	YC164-JR-0710KL	DIST DIGIKEY YC164J-10KCT-ND	RESPACK SMD 10k 5% [4x0603]
R85	Yageo	YC164-JR-0710KL	DIST DIGIKEY YC164J-10KCT-ND	RESPACK SMD 10k 5% [4x0603]

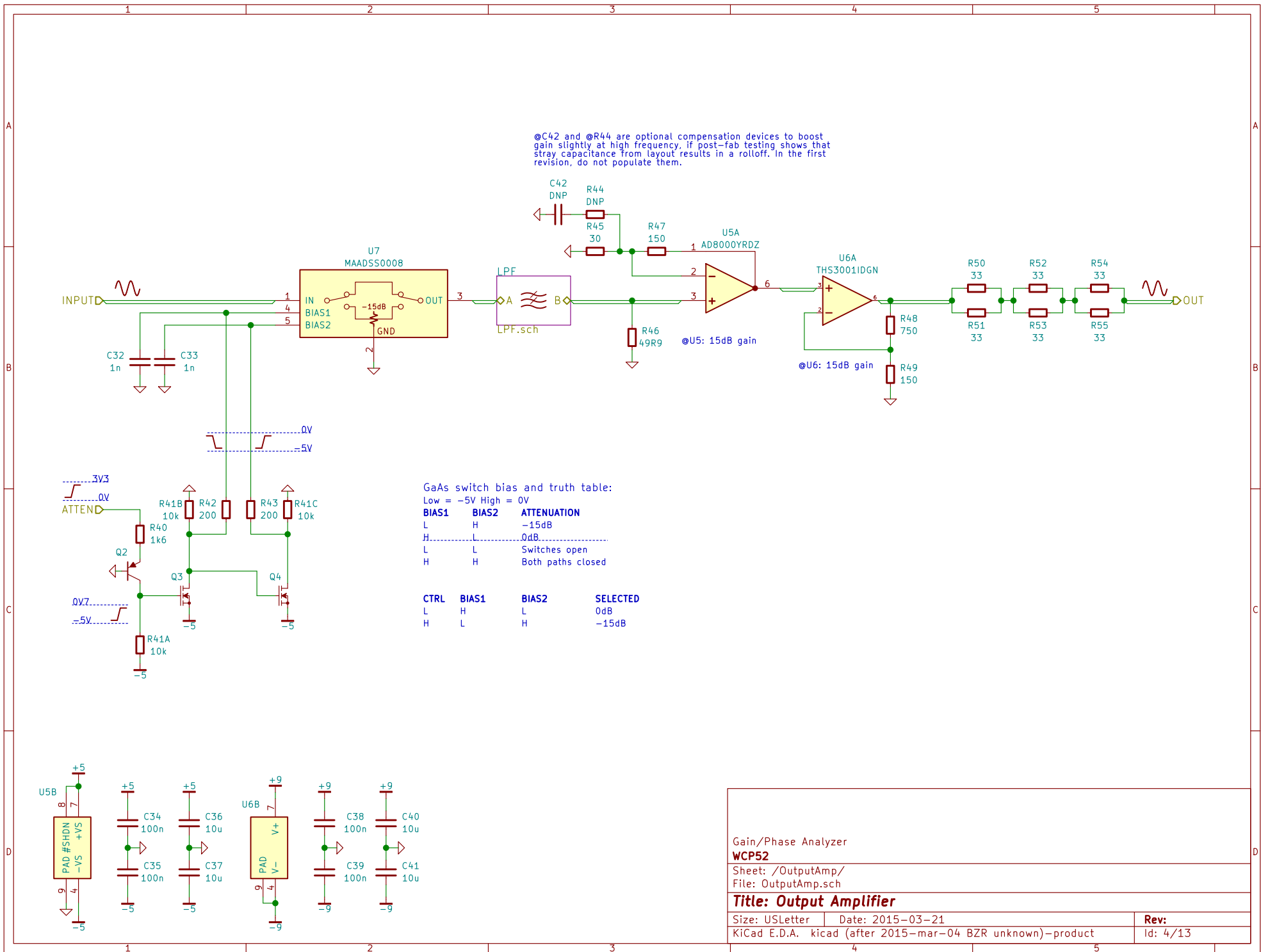
Reference	Manufacturer	Part Number	Line	Description
R86			RES SMD 3k3 5% [0603]	
R87			RES SMD 1M 5% [0603]	
R88			RES SMD 1M 5% [0603]	
R89			RES SMD 3k3 5% [0603]	
R90			RES SMD 3k3 5% [0603]	
R91			RES SMD 1k6 1% [0603]	
R92			RES SMD 750 1% [0603]	
R93			RES SMD 1k6 1% [0603]	
R94			RES SMD 750 1% [0603]	
R95			RES SMD 1 5% [1210]	
R96			RES SMD 1 5% [1210]	
R97	BelFuse	0ZCJ0010FF2E	DIST DIGIKEY 507-1794-1-ND	PPTC 100mA/250mA 60V [1206]
R98			RES SMD 3R3 10% [0603]	
R99			RES SMD 3R3 10% [0603]	
R102			RES SMD 3k3 5% [0603]	
R103			RES SMD 3k3 5% [0603]	
R104			RES SMD 3k3 5% [0603]	
R105			RES SMD 3k3 5% [0603]	
R106			RES SMD 1k 5% [0603]	
R107			RES SMD 1k 5% [0603]	
R108			RES SMD 1k 5% [0603]	
R109			RES SMD 1k 5% [0603]	
R110			RES SMD 200 1% [0603]	
R111			RES SMD 3k3 5% [0603]	
R112			RES SMD 200 1% [0603]	
R113			RES SMD 200 1% [0603]	
R114			RES SMD 200 1% [0603]	
R115			RES SMD 200 1% [0603]	
R116			RES SMD 200 1% [0603]	
R117			RES SMD 360 1% [0603]	
U2			IC TI LMH6714MF	
U3			IC ADI AD9958BCPZ	
U4			IC TI LMH6714MF	
U5			IC ADI AD8000YRDZ	
U6			IC TI THS3001IDGN	
U7			IC MACOM MAADSS0008	
U8			IC MACOM MASWSS0162	

Reference	Manufacturer	Part Number	Line	Description
U9			IC MACOM MASWSS0162	
U10			IC ADI AD8310ARMZ	
U11			IC TI TL431AIDBZ	
U12			IC GENERIC LM393M	
U13			IC ST L78M05CDT	
U14			IC ONSEMI MC79M05CDTG	
U15			IC DIODES AZ1117CH-1.8TRG1	
U16			IC MICROCHIP MCP1700T-3302E/TT	
U18			IC ATMEL ATSAM4S16CA-AU	
X1	TXC	9C-25.000MEEJ-T	DIST DIGIKEY 887-1283-1-ND	CRYSTAL 25MHz 18pF 10PPM
X2	Abracon	ABLS-12.000MHZ-B4-T	DIST DIGIKEY 535-10218-1-ND	CRYSTAL 12MHz 18pF

6 Full schematics

The following pages contain schematics exported directly from the CAD software. While they are documented, it is intended that readers will first familiarize themselves with the workings of the circuits by reading through the [Theory of Operation](#).





Gain/Phase Analyzer

WCP52

Sheet: /OutputAmp/

File: OutputAmp.sch

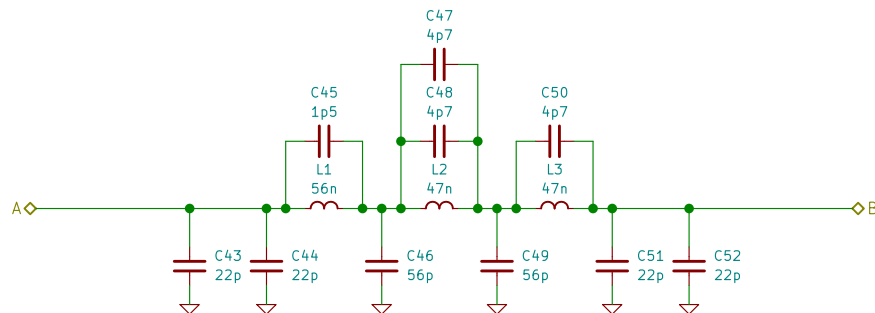
Title: Output Amplifier

Size: USLetter Date: 2015-03-21

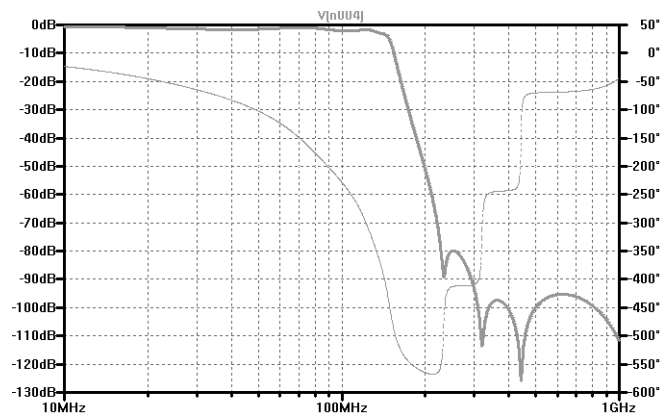
KiCad E.D.A. kicad (after 2015-mar-04 BZR unknown)-product

Rev:

Id: 4/13



Intended frequency response of filter:



Gain/Phase Analyzer

WCP52

Sheet: /OutputAmp/LPF/

File: LPF.sch

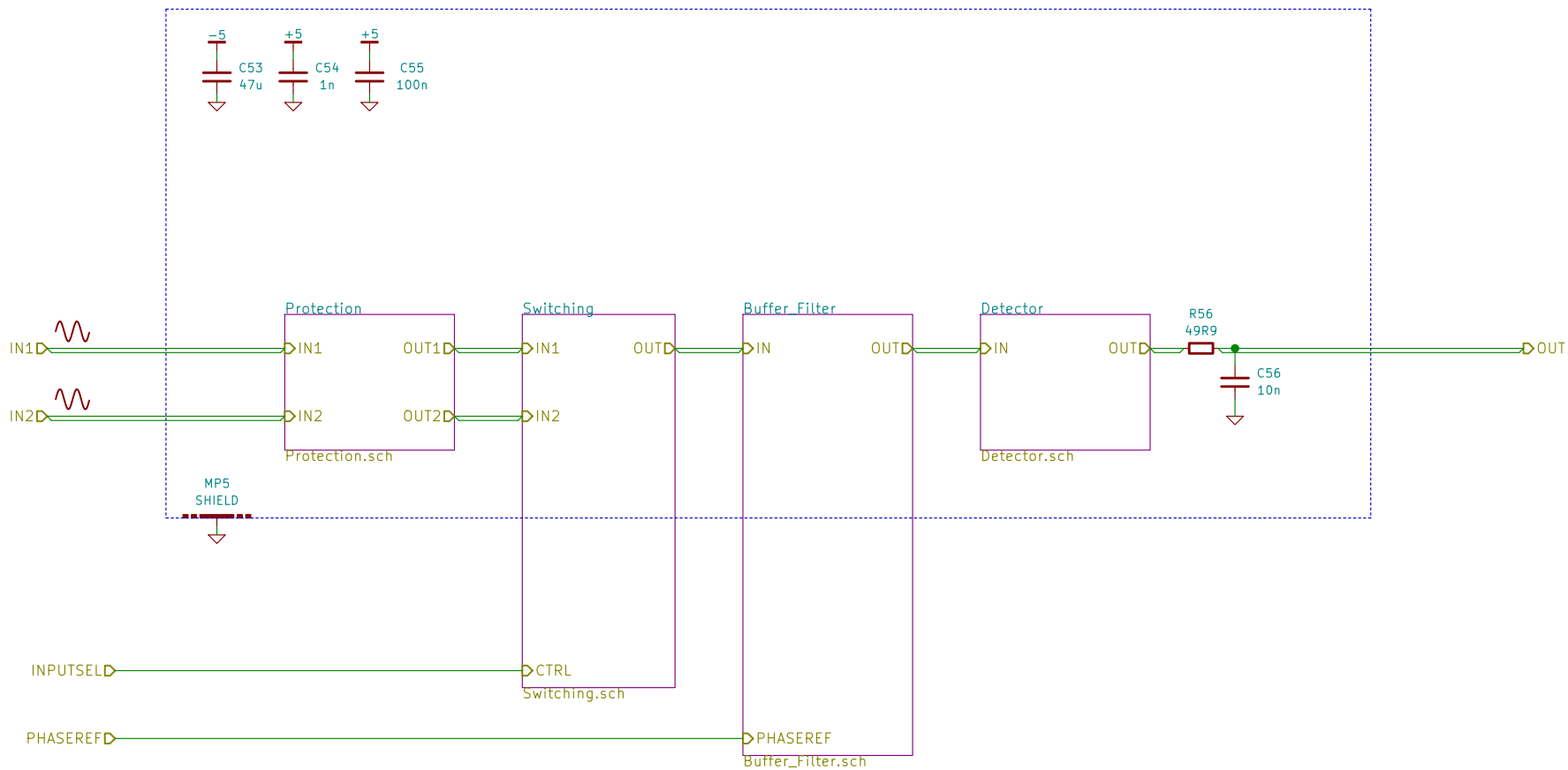
Title: LPF for Output Amplifier

Size: USLetter Date: 2015-03-21

KiCad E.D.A. kicad (after 2015-mar-04 BZR unknown)-product

Rev:

Id: 5/13



Gain/Phase Analyzer

WCP52

Sheet: /InputFrontend/

File: InputFrontend.sch

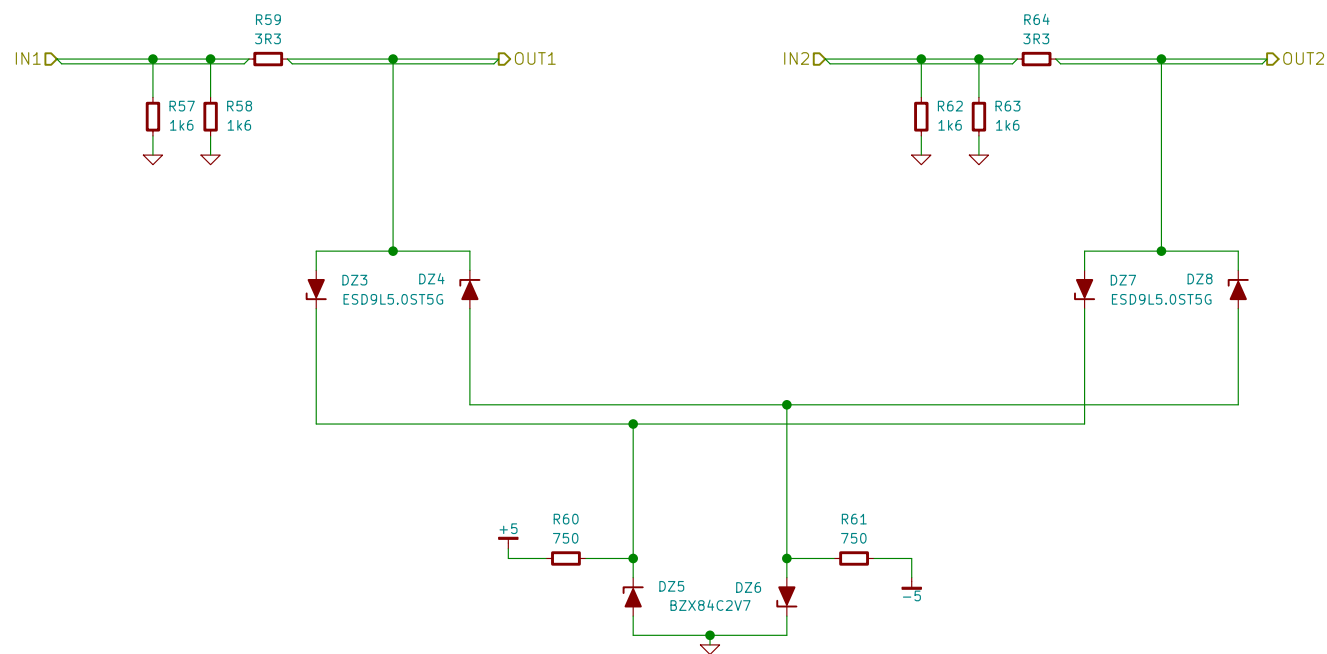
Title: Input Frontend

Size: USLetter Date: 2015-03-21

KiCad E.D.A. kicad (after 2015-mar-04 BZR unknown)-product

Rev:

Id: 6/13



Gain/Phase Analyzer

WCP52

Sheet: /InputFrontend/Protection/

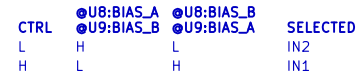
File: Protection.sch

Title: Input Protection

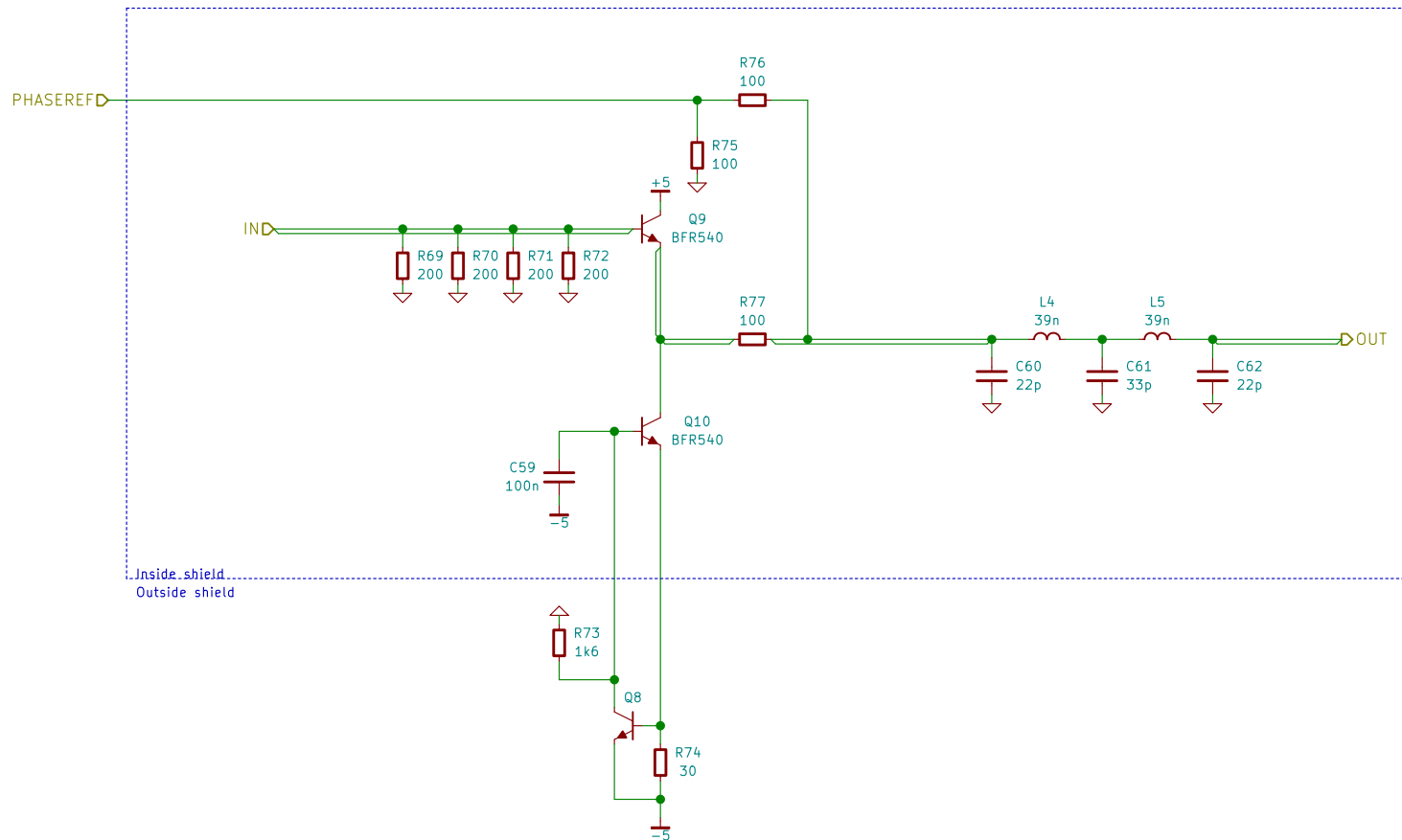
Size: USLetter Date: 2015-03-21

KiCad E.D.A. kicad (after 2015-mar-04 BZR unknown)-product

Rev:
Id: 7/13



Rev:
Id: 8/13



Gain/Phase Analyzer

WCP52

Sheet: /InputFrontend/Buffer_Filter/

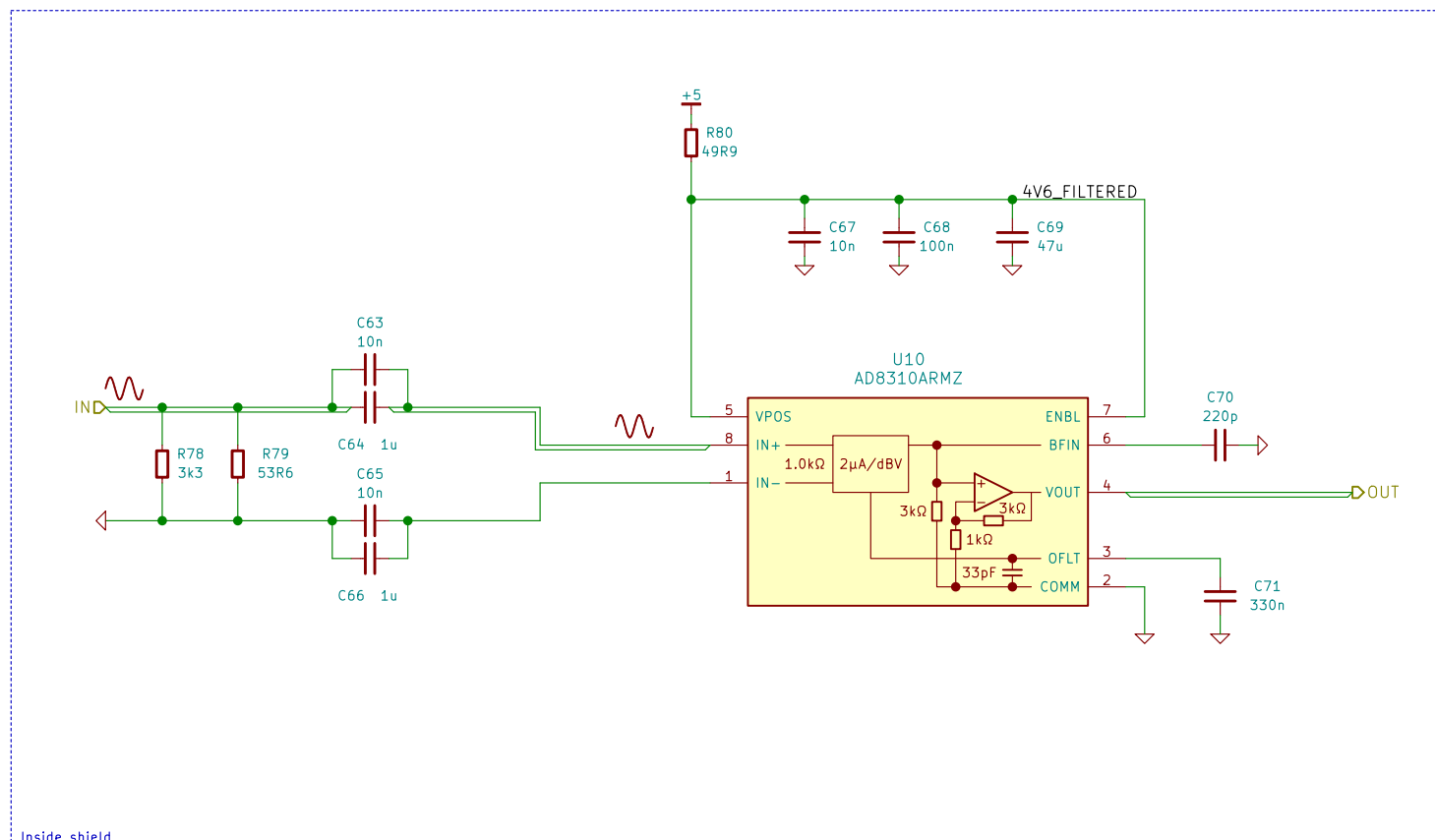
File: Buffer_Filter.sch

Title: Input Buffer and Filter

Size: USLetter Date: 2015-03-21

KiCad E.D.A. kicad (after 2015-mar-04 BZR unknown)-product

Rev:
Id: 9/13



Gain/Phase Analyzer

WCP52

Sheet: /InputFrontend/Detector/

File: Detector.sch

Title: Logarithmic Detector

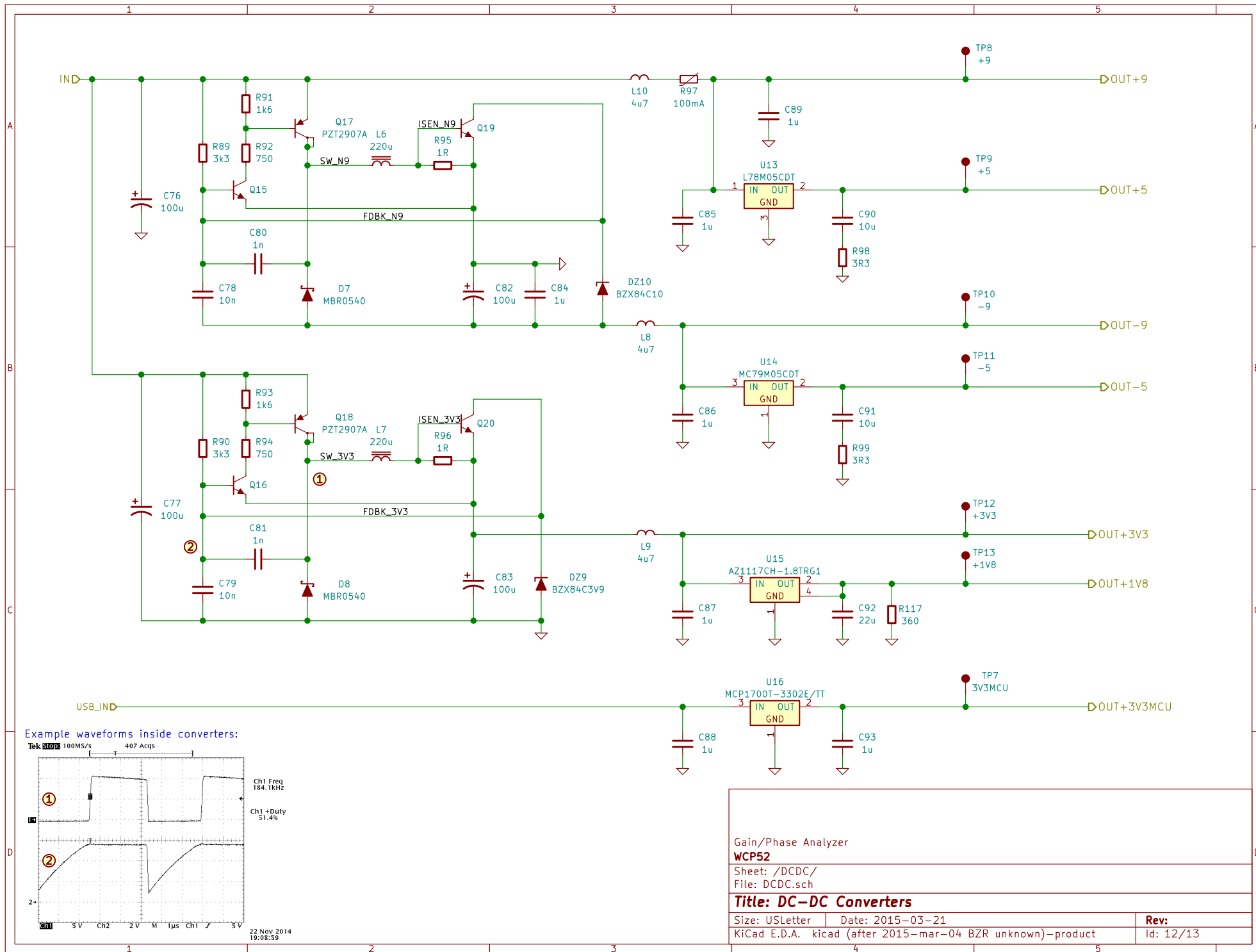
Size: USLetter Date: 2015-03-21

KiCad E.D.A. kicad (after 2015-mar-04 BZR unknown)-product

Rev:

Id: 10/13

Id: 11/13



References

- [1] Alpha & Omega Semiconductor, “AOD417 P-Channel Enhancement Mode Field Effect Transistor,” AOD417 datasheet, 2008. <http://aosmd.com/pdfs/datasheet/AOD417.pdf>
- [2] S. W. Amos and M. James, “Sawtooth generators,” in *Principles of Transistor Circuits*, 9th ed. Oxford: Newnes, 2003, ch. 14, pp. 281–292.
- [3] Analog Devices, Inc., “2-Channel, 500 MSPS DDS with 10-Bit DACs,” AD9958 datasheet, April 2013 [Revision B]. <http://www.analog.com/media/cn/technical-documentation/data-sheets/AD9958.pdf>
- [4] Diodes Incorporated, “Low Dropout Linear Regulator,” AZ1117C datasheet, October 2014 [Revision 3–2]. <http://www.diodes.com/datasheets/AZ1117C.pdf>
- [5] P. Horowitz and W. Hill, “Voltage regulators and power circuits,” in *The Art of Electronics*, 2nd ed. Cambridge: Cambridge, 1989, ch. 6, pp. 307–389.
- [6] M/A-COM Technology, “GaAs SPST Switch,” MASWSS0162 datasheet [Revision V3]. <http://cdn.macom.com/DataSheets/MASWSS0162.pdf>
- [7] Microchip Technology, “Low Quiescent Current LDO,” MCP1700 datasheet, October 2013 [Revision C]. <http://ww1.microchip.com/downloads/en/DeviceDoc/20001826C.pdf>
- [8] ON Semiconductor, “500 mA Negative Voltage Regulators,” MC79M00 series datasheet, July 2013 [Revision 15]. http://www.onsemi.com/pub_link/Collateral/MC79M00-D.PDF.
- [9] STMicroelectronics, “Precision 500 mA regulators,” L78M datasheet, June 2014 [Revision 20]. <http://www.st.com/web/en/resource/technical/document/datasheet/CD00000447.pdf>
- [10] Texas Instruments, “TL43xx Precision Programmable Reference,” TL431 datasheet, Aug. 2004 [Revised Jan. 2015]. <http://www.ti.com/lit/ds/symlink/tl431.pdf>
- [11] J. Tucker, “Using a buck converter in an inverting buck-boost topology,” *Analog Applications Journal*, Texas Instruments, fourth quarter 2007, pp. 16–19. <http://www.ti.com/lit/an/slyt286/slyt286.pdf>